

**Features :**

- Isolated mounting base 2500V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving
- UL Recognized

Typical Applications

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

| V_{DSM}, V_{RSM} | V_{DRM}, V_{RRM} | Type |
|--------------------|--------------------|------------|
| 900V | 800V | DSKT800/08 |
| 1100V | 1000V | DSKT800/10 |
| 1300V | 1200V | DSKT800/12 |
| 1500V | 1400V | DSKT800/14 |
| 1700V | 1600V | DSKT800/16 |
| 1900V | 1800V | DSKT800/18 |

| SYMBOL | CHARACTERISTIC | TEST CONDITIONS | $T_j(^{\circ}\text{C})$ | VALUE | | | UNIT |
|------------------------|--|--|-------------------------|-------|------|-------|----------------------------------|
| | | | | Min | Type | Max | |
| $I_{T(AV)}$ | Mean on-state current | 180° half sine wave 50Hz Single side cooled, $T_c=85^{\circ}\text{C}$ | 125 | | | 800 | A |
| $I_{T(RMS)}$ | RMS on-state current | | | | | 1256 | A |
| I_{DRM} I_{RRM} | Repetitive peak current | at V_{DRM} at V_{RRM} | 125 | | | 45 | mA |
| I_{TSM} | Surge on-state current | 10ms half sine wave $V_R=0.6V_{RRM}$ | 125 | | | 22.0 | kA |
| I^{2t} | I^{2t} for fusing coordination | | | | | 2420 | $\text{A}^2\text{s} \times 10^3$ |
| V_{TO} | Threshold voltage | | 125 | | | 0.80 | V |
| r_T | On-state slope resistance | | | | | 0.20 | $\text{m}\Omega$ |
| V_{TM} | Peak on-state voltage | $I_{TM}=2400\text{A}$ | 25 | | | 1.86 | V |
| dv/dt | Critical rate of rise of off-state voltage | $V_{DM}=67\%V_{DRM}$ | 125 | | | 800 | $\text{V}/\mu\text{s}$ |
| di/dt | Critical rate of rise of on-state current | Gate source 1.5A $t_r \leq 0.5\mu\text{s}$ Repetitive | 125 | | | 100 | $\text{A}/\mu\text{s}$ |
| I_{GT} | Gate trigger current | $V_A=12\text{V}$, $I_A=1\text{A}$ | 25 | 30 | | 200 | mA |
| V_{GT} | Gate trigger voltage | | | 0.8 | | 3.0 | V |
| I_H | Holding current | | | 10 | | 200 | mA |
| V_{GD} | Non-trigger gate voltage | $V_{DM}=67\%V_{DRM}$ | 125 | 0.2 | | | V |
| $R_{th(j-c)}$ | Thermal resistance Junction to case | Single side cooled per chip | | | | 0.042 | $^{\circ}\text{C}/\text{W}$ |
| $R_{th(c-h)}$ | Thermal resistance case to heatsink | Single side cooled per chip | | | | 0.020 | $^{\circ}\text{C}/\text{W}$ |
| V_{iso} | Isolation voltage | 50Hz, R.M.S, $t=1\text{min}$, $I_{iso}=1\text{mA}(\text{MAX})$ | | 2500 | | | V |
| F_m | Terminal connection torque(M12) | | | | 14.0 | | $\text{N}\cdot\text{m}$ |
| | Mounting torque(M8) | | | | 12.0 | | $\text{N}\cdot\text{m}$ |
| T_{vj} | Junction temperature | | | -40 | | 125 | $^{\circ}\text{C}$ |
| T_{stg} | Stored temperature | | | -40 | | 125 | $^{\circ}\text{C}$ |
| W_t | Weight | | | | 3240 | | g |
| | | | | | | | |

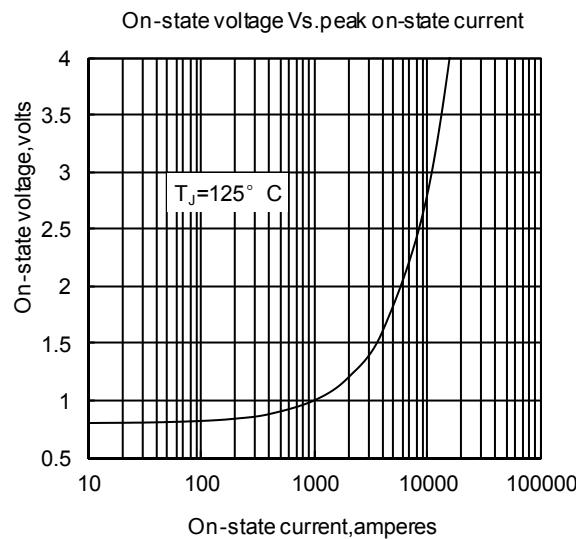


Fig1

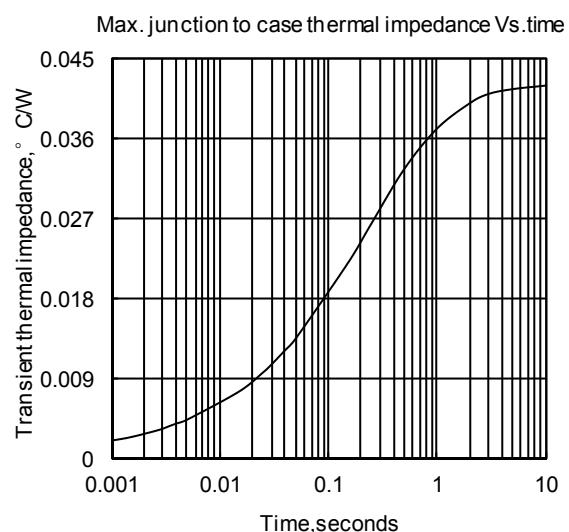


Fig2

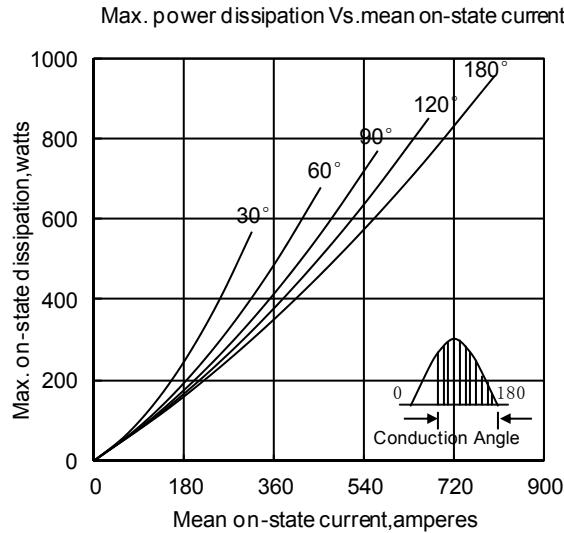


Fig3

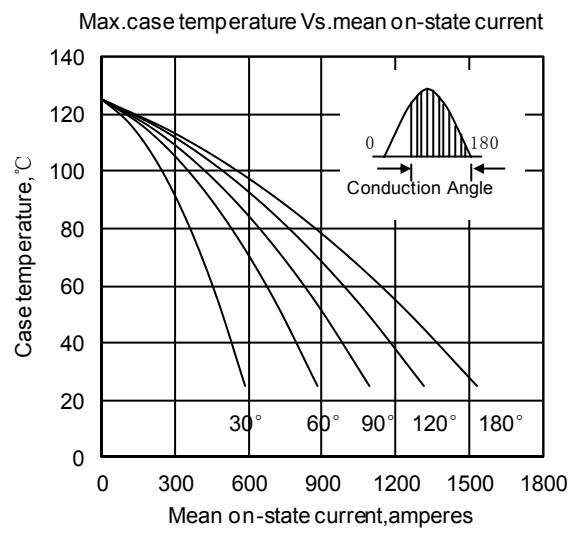


Fig4

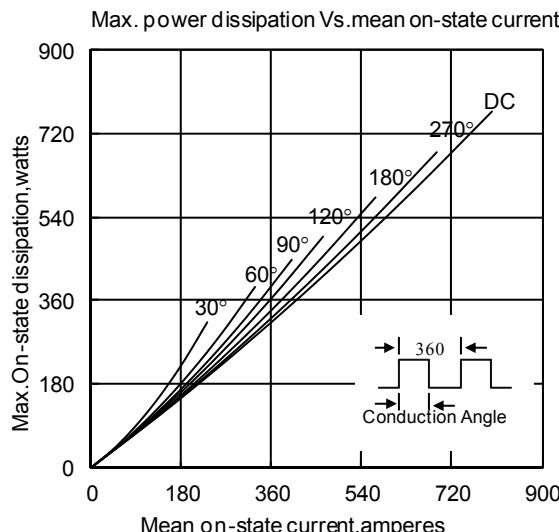


Fig5

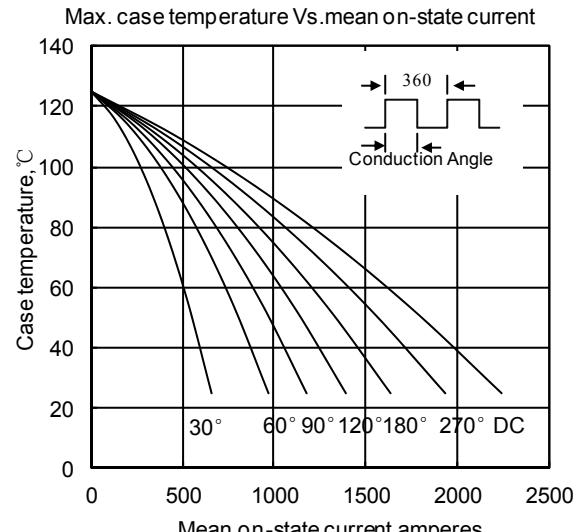


Fig6

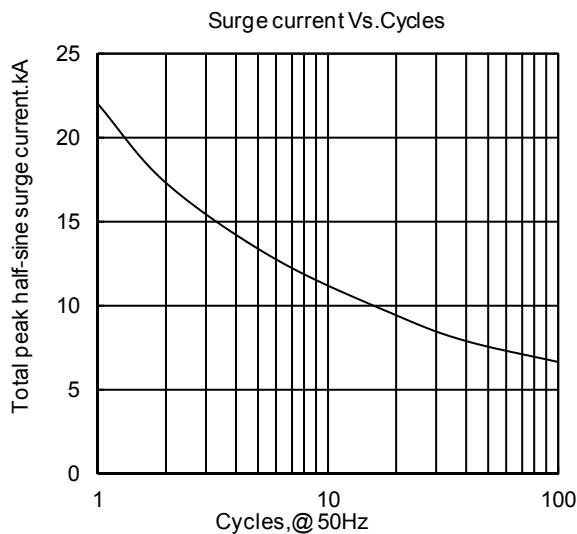


Fig7

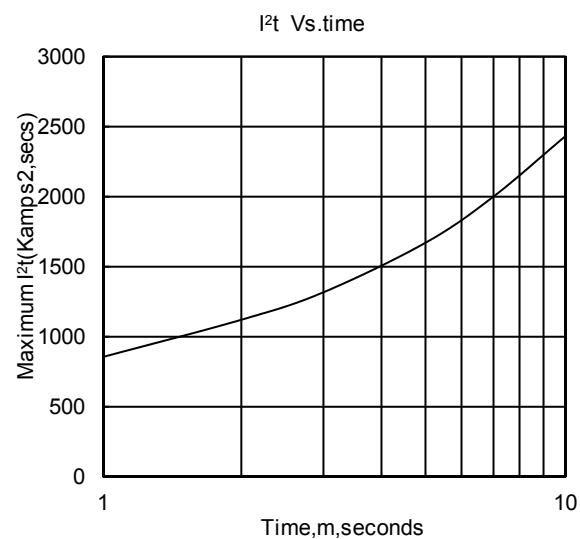


Fig8

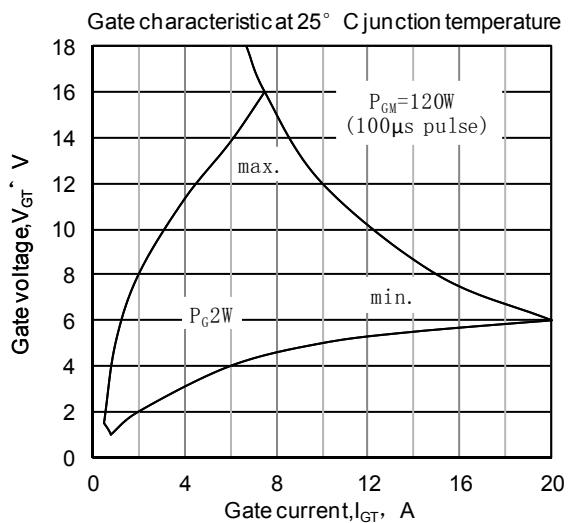


Fig9

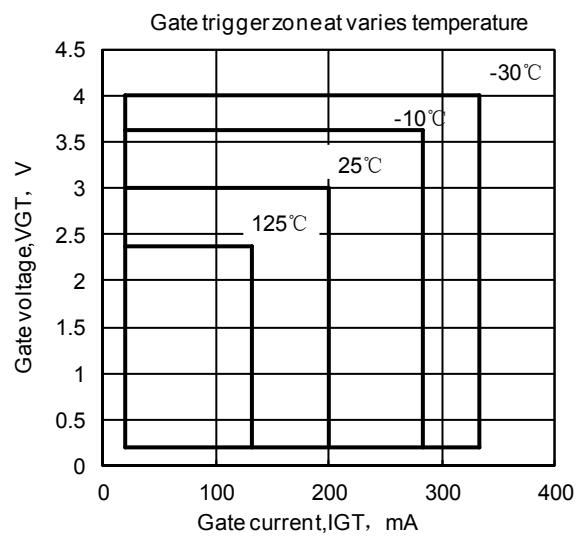


Fig10

Outline:

